Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Plastic

# Overall Length:

Between 0.205 inches and 0.220 inches

# **Overall Height:**

Between 0.075 inches and 0.095 inches

## **Overall Width:**

Between 0.130 inches and 0.150 inches

## **End Application:**

Aau, air combat maneuvering instruments

## **Mounting Method:**

Terminal

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

13.0 regulator voltage

## Voltage Tolerance In Percent:

-5.0/+5.0

## **Current Rating Per Characteristic:**

28.80 milliamperes all primaries horsepower metric and 115.00 milliamperes repetitive peak forward current

## **Power Rating Per Characteristic:**

3.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Terminal Type And Quantity:**

2 ribbon

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

# Fiig:

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